

2K x 8 Dual-Port Static RAM

Features

- True Dual-Ported memory cells which allow simultaneous reads of the same memory location
- 2K x 8 organization
- 0.65-micron CMOS for optimum speed/power
- High-speed access: 15 ns
- Low operating power: I_{CC} = 110 mA (max.)
- Fully asynchronous operation
- · Automatic power-down
- Master CY7C132/CY7C136 easily expands data bus width to 16 or more bits using slave CY7C142/CY7C146
- BUSY output flag on CY7C132/CY7C136; BUSY input on CY7C142/CY7C146
- INT flag for port-to-port communication (52-pin PLCC/PQFP versions)
- Available in 48-pin DIP (CY7C132/142), 52-pin PLCC and 52-pin TQFP (CY7C136/146)

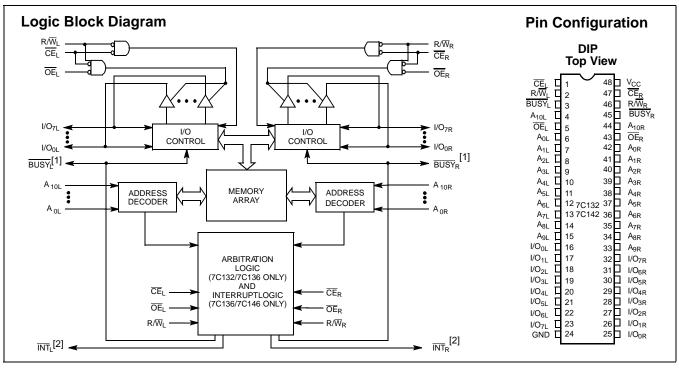
Functional Description

The CY7C132/CY7C136/CY7C142 and CY7C146 are high-speed CMOS 2K by 8 dual-port static RAMs. Two ports are provided to permit independent access to any location in memory. The CY7C132/ CY7C136 can be utilized as either a standalone 8-bit dual-port static RAM or as a MASTER dual-port RAM in conjunction with the CY7C142/CY7C146 SLAVE dual-port device in systems requiring 16-bit or greater word widths. It is the solution to applications requiring shared or buffered data such as cache memory for DSP, bit-slice, or multiprocessor designs.

Each port has <u>independent</u> control pins; <u>chip enable</u> (\overline{CE}), write enable (R/W), and output enable (\overline{OE}). BUSY flags are provided on each port. In addition, an interrupt flag (\overline{INT}) is provided on each port of the 52-pin PLCC version. BUSY signals that the port is trying to access the same location currently being accessed by the other port. On the PLCC version, \overline{INT} is an interrupt flag indicating that data has been placed in a unique location (7FF for the left port and 7FE for the right port).

An automatic power-down feature is controlled independently on each port by the chip enable (CE) pins.

The CY7C132/CY7C142 are available in 48-pin DIP. The CY7C136/CY7C146 are available in 52-pin PLCC and PQFP.

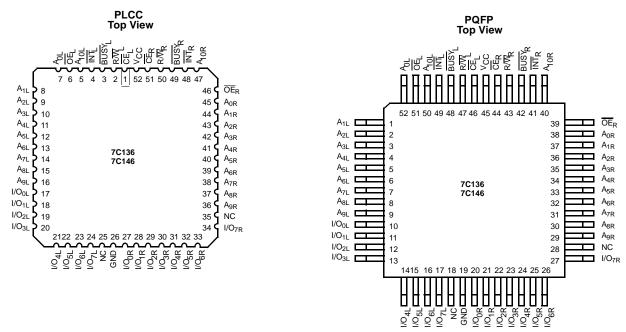


Notes:

- CY7C132/CY7C136 (Master): BUSY is open drain output and requires pull-up resistor. CY7C142/CY7C146 (Slave): BUSY is input.
- Open drain outputs; pull-up resistor required.



Pin Configurations



Selection Guide

| | | 7C136-15 ^[3] 7C146-15 | 7C132-25 ^[3] 7C136-25 7C142-25 7C146-25 | 7C132-30 7C136-30 7C142-30 7C146-30 | 7C132-35 7C136-35 7C142-35 7C146-35 | 7C132-45 7C136-45 7C142-45 7C146-45 | 7C132-55 7C136-55 7C142-55 7C146-55 | Unit |
|---------------------------|-----------|-------------------------------------|-------------------------------------------------------------|----------------------------------------------|----------------------------------------------|----------------------------------------------|----------------------------------------------|------|
| Maximum Access Time | | 15 | 25 | 30 | 35 | 45 | 55 | ns |
| Maximum Operating Current | Com'l/Ind | 190 | 170 | 170 | 120 | 120 | 110 | mA |
| Maximum Operating Current | Military | | | | 170 | 170 | 120 | mA |
| Maximum Standby Current | Com'l/Ind | 75 | 65 | 65 | 45 | 45 | 35 | mA |
| | Military | | | | 65 | 65 | 45 | |

Shaded area contains preliminary information.

Note:

3. 15 and 25-ns version available in PQFP and PLCC packages only.



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.) Storage Temperature-65°C to +150°C Ambient Temperature with Supply Voltage to Ground Potential (Pin 48 to Pin 24).....-0.5V to +7.0V DC Voltage Applied to Outputs in High-Z State—0.5V to +7.0V

| DC Input Voltage | 3.5V to +7.0V |
|--------------------------------------------------------|---------------|
| Output Current into Outputs (LOW) | 20 mA |
| Static Discharge Voltage(per MIL-STD-883, Method 3015) | >2001V |
| Latch-up Current | > 200 mA |

Operating Range

| Range | Ambient Temperature | V _{CC} |
|-------------------------|---------------------|-----------------|
| Commercial | 0°C to +70°C | 5V ± 10% |
| Industrial | -40°C to +85-C | 5V ± 10% |
| Military ^[4] | −55°C to +125°C | 5V ± 10% |

Electrical Characteristics Over the Operating Range^[5]

| | | | | | 6-15 ^[3] 46-15 | 7C136 | 5-25,30 12-30 | 7C130 | 2-35,45 6-35,45 2-35,45 6-35,45 | 7C13 | 32-55 36-55 42-55 46-55 | |
|------------------|---------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------|----------------|------------------------------|-------|------------------|-------|------------------------------------------|------------|----------------------------------|------|
| Parameter | Description | Test Conditions | | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| V _{OH} | Output HIGH voltage | $V_{CC} = Min., I_{OH} = -4.0 \text{ mA}$ | | 2.4 | | 2.4 | | 2.4 | | 2.4 | | V |
| V _{OL} | Output LOW voltage | $I_{OL} = 4.0 \text{ mA}$ | | | 0.4 | | 0.4 | | 0.4 | | 0.4 | V |
| | | $I_{OL} = 16.0 \text{ mA}^{[6]}$ | | | 0.5 | | 0.5 | | 0.5 | | 0.5 | |
| V _{IH} | Input HIGH voltage | | | 2.2 | | 2.2 | | 2.2 | | 2.2 | | V |
| V _{IL} | Input LOW voltage | | | | 0.8 | | 0.8 | | 0.8 | | 0.8 | V |
| I _{IX} | Input load current | $GND \le V_1 \le V_{CC}$ | | - 5 | +5 | -5 | +5 | -5 | +5 | -5 | +5 | μΑ |
| I _{OZ} | Output leakage current | $GND \le V_O \le V_{CC}$, Output Disabled | | - 5 | +5 | -5 | +5 | -5 | +5 | - 5 | +5 | μΑ |
| I _{OS} | Output short circuit current ^[7] | V _{CC} = Max., V _{OUT} = GND | | | -350 | | -350 | | -350 | | -350 | mA |
| I _{CC} | V _{CC} Operating | CE = V _{IL} , Outputs Open, f = | Com'l | | 190 | | 170 | | 120 | | 110 | mA |
| | Supply Current | f _{MAX} ^[8] | Mil | | | | | | 170 | | 120 | |
| I _{SB1} | Standby current both | CE_L and $\overline{CE}_R \ge V_{IH}$, $f = f_{MAX}^{[8]}$ | Com'l | | 75 | | 65 | | 45 | | 35 | mA |
| | ports, TTL Inputs | $f = f_{MAX}^{[O]}$ | Mil | | | | | | 65 | | 45 | |
| I _{SB2} | Standby Current | $\overline{CE_L}$ or $\overline{CE_R} \ge V_{IH}$, | Com'l | | 135 | | 115 | | 90 | | 75 | mA |
| | One Port, TTL Inputs | Active Port Outputs Open, f = f _{MAX} ^[8] | Mil | | | | | | 115 | | 90 | |
| I _{SB3} | Standby Current | Both Ports CE _L and | Com'l | | 15 | | 15 | | 15 | | 15 | mA |
| | Both Ports, CMOS Inputs | $CE_R \ge V_{CC} - 0.2V$, $V_{IN} \ge V_{CC} - 0.2V$ or $V_{IN} \le 0.2V$, $f = 0$ | Mil | | | | | | 15 | | 15 | |
| I _{SB4} | Standby Current | One Port CEL or CER > V _{CC} - | Com'l | | 125 | | 105 | | 85 | | 70 | mΑ |
| | One Port, CMOS Inputs | $\begin{array}{l} 0.2\text{V, V}_{\text{IN}} > \text{V}_{\text{CC}} - 0.2\text{V or V}_{\text{IN}} < \\ 0.2\text{V, Active Port Outputs Open,} \\ \text{f} = \text{f}_{\text{MAX}}^{[8]} \end{array}$ | Mil | | | | | | 105 | | 85 | |

Capacitance^[9]

| Parameter | Description | Test Conditions | Max. | Unit |
|------------------|--------------------|-----------------------------------------|------|------|
| C _{IN} | Input Capacitance | $T_A = 25^{\circ}C, f = 1 \text{ MHz},$ | 15 | pF |
| C _{OUT} | Output Capacitance | $V_{CC} = 5.0V$ | 10 | pF |

Shaded area contains preliminary information.

Notes:

4. T_A is the "instant on" case temperature.

See the last page of this specification for Group A subgroup testing information. BUSY and INT pins only.

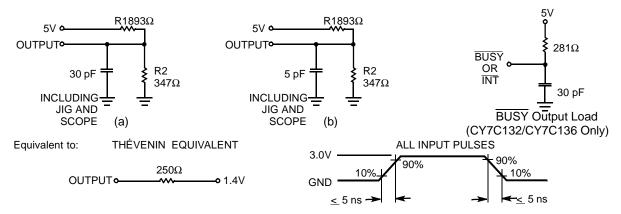
Duration of the short circuit should not exceed 30 seconds.

At $f=f_{MAX}$, address and data inputs are cycling at the maximum frequency of read cycle of $1/t_{rc}$ and using AC Test Waveforms input levels of GND to 3V.

This parameter is guaranteed but not tested.



AC Test Loads and Waveforms



Switching Characteristics Over the Operating Range (Speeds -15, -25, -30) [5, 10]

| | | | 6-15 ^[3] 46-15 | 7C1: 7C1: | 2-25 ^[3] 36-25 42-25 46-25 | 7C1: 7C1 | 32-30 36-30 42-30 46-30 | |
|---------------------------|------------------------------------------|------|------------------------------|--------------|------------------------------------------------|-------------|----------------------------------|------|
| Parameter | Description | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| Read Cycle | | | | | | | | |
| t _{RC} | Read Cycle Time | 15 | | 25 | | 30 | | ns |
| t _{AA} | Address to Data Valid ^[11] | | 15 | | 25 | | 30 | ns |
| t _{OHA} | Data Hold from Address Change | 0 | | 0 | | 0 | | ns |
| t _{ACE} | CE LOW to Data Valid ^[11] | | 15 | | 25 | | 30 | ns |
| t _{DOE} | OE LOW to Data Valid ^[11] | | 10 | | 15 | | 20 | ns |
| t _{LZOE} | OE LOW to Low Z ^[9, 12] | 3 | | 3 | | 3 | | ns |
| t _{HZOE} | OE HIGH to High Z ^[9, 12, 13] | | 10 | | 15 | | 15 | ns |
| t _{LZCE} | CE LOW to Low Z ^[9, 12] | 3 | | 5 | | 5 | | ns |
| t _{HZCE} | CE HIGH to High Z ^[9, 12, 13] | | 10 | | 15 | | 15 | ns |
| t _{PU} | CE LOW to Power-Up ^[9] | 0 | | 0 | | 0 | | ns |
| t _{PD} | CE HIGH to Power-Down ^[9] | | 15 | | 25 | | 25 | ns |
| Write Cycle ^{[1} | 4] | | • | | • | | 1. | |
| t _{WC} | Write Cycle Time | 15 | | 25 | | 30 | | ns |
| t _{SCE} | CE LOW to Write End | 12 | | 20 | | 25 | | ns |
| t _{AW} | Address Set-up to Write End | 12 | | 20 | | 25 | | ns |
| t _{HA} | Address Hold from Write End | 2 | | 2 | | 2 | | ns |
| t _{SA} | Address Set-up to Write Start | 0 | | 0 | | 0 | | ns |
| t _{PWE} | R/W Pulse Width | 12 | | 15 | | 25 | | ns |
| t _{SD} | Data Set-up to Write End | 10 | | 15 | | 15 | | ns |
| t _{HD} | Data Hold from Write End | 0 | | 0 | | 0 | | ns |
| t _{HZWE} | R/W LOW to High Z ^[9] | | 10 | | 15 | | 15 | ns |
| t _{LZWE} | R/W HIGH to Low Z ^[9] | 0 | | 0 | | 0 | | ns |

Shaded areas contain preliminary information.

Notes:

Test conditions assume signal transition times of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V and output loading of the specified loL/loH, and 30-pF load capacitance.
 AC test conditions use V_{OH} = 1.6V and V_{OL} = 1.4V.
 At any given temperature and voltage condition for any given device, t_{HZCE} is less than t_{LZCE} and t_{HZOE} is less than t_{LZCE}.
 t_{LZCE}, t_{LZOE}, t_{HZOE}, t_{LZOE}, t_{HZCE}, and t_{HZWE} are tested with C_L = 5pF as in (b) of AC Test Loads. Transition is measured ±500 mV from steady-state voltage.
 The internal write time of the memory is defined by the overlap of CE LOW and R/W LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input setup and hold timing should be referenced to the rising edge of the signal that terminates the write.



Switching Characteristics Over the Operating Range (Speeds -15, -25, -30) (continued)^[5, 10]

| | | | 6-15 ^[3] 46-15 | 7C1 7C1 | 2-25 ^[3] 36-25 42-25 46-25 | 7C1: 7C1 | 32-30 36-30 42-30 46-30 | |
|-------------------|-------------------------------------------------|------|------------------------------|------------|------------------------------------------------|-------------|----------------------------------|------|
| Parameter | Description | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| Busy/Interrup | ot Timing | • | • | | | | | |
| t _{BLA} | BUSY LOW from Address Match | | 15 | | 20 | | 20 | ns |
| t _{BHA} | BUSY HIGH from Address Mismatch ^[15] | | 15 | | 20 | | 20 | ns |
| t _{BLC} | BUSY LOW from CE LOW | | 15 | | 20 | | 20 | ns |
| t _{BHC} | BUSY HIGH from CE HIGH ^[15] | | 15 | | 20 | | 20 | ns |
| t _{PS} | Port Set Up for Priority | 5 | | 5 | | 5 | | ns |
| t _{WB} | R/W LOW after BUSY LOW[16] | 0 | | 0 | | 0 | | ns |
| t _{WH} | R/W HIGH after BUSY HIGH | 13 | | 20 | | 30 | | ns |
| t _{BDD} | BUSY HIGH to Valid Data | | 15 | | 25 | | 30 | ns |
| t _{DDD} | Write Data Valid to Read Data Valid | | Note 17 | | Note 17 | | Note 17 | ns |
| t _{WDD} | Write Pulse to Data Delay | | Note 17 | | Note 17 | | Note 17 | ns |
| Interrupt Tim | ing ^[18] | | ' | | | | | |
| t _{WINS} | R/W to INTERRUPT Set Time | | 15 | | 25 | | 25 | ns |
| t _{EINS} | CE to INTERRUPT Set Time | | 15 | | 25 | | 25 | ns |
| t _{INS} | Address to INTERRUPT Set Time | | 15 | | 25 | | 25 | ns |
| t _{OINR} | OE to INTERRUPT Reset Time ^[15] | | 15 | | 25 | | 25 | ns |
| t _{EINR} | CE to INTERRUPT Reset Time ^[15] | | 15 | | 25 | | 25 | ns |
| t _{INR} | Address to INTERRUPT Reset Time ^[15] | | 15 | | 25 | | 25 | ns |

Switching Characteristics Over the Operating Range (Speeds -35, -45, -55) [5, 10]

| | | 7C132-35 7C136-35 7C142-35 7C146-35 | | 7C132-45 7C136-45 7C142-45 7C146-45 | | 7C132-55 7C136-55 7C142-55 7C146-55 | | |
|-------------------|------------------------------------------|----------------------------------------------|------|----------------------------------------------|------|----------------------------------------------|------|------|
| Parameter | Description | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| Read Cycle | | • | | • | | • | • | |
| t _{RC} | Read Cycle Time | 35 | | 45 | | 55 | | ns |
| t _{AA} | Address to Data Valid ^[11] | | 35 | | 45 | | 55 | ns |
| t _{OHA} | Data Hold from Address Change | 0 | | 0 | | 0 | | ns |
| t _{ACE} | CE LOW to Data Valid ^[11] | | 35 | | 45 | | 55 | ns |
| t _{DOE} | OE LOW to Data Valid ^[11] | | 20 | | 25 | | 25 | ns |
| t _{LZOE} | OE LOW to Low Z ^[9, 12] | 3 | | 3 | | 3 | | ns |
| t _{HZOE} | OE HIGH to High Z ^[9, 12, 13] | | 20 | | 20 | | 25 | ns |
| t _{LZCE} | CE LOW to Low Z ^[9, 12] | 5 | | 5 | | 5 | | ns |
| t _{HZCE} | CE HIGH to High Z ^[9, 12, 13] | | 20 | | 20 | | 25 | ns |
| t _{PU} | CE LOW to Power-Up ^[9] | 0 | | 0 | | 0 | | ns |
| t _{PD} | CE HIGH to Power-Down ^[9] | | 35 | | 35 | | 35 | ns |

- 15. These parameters are measured from the input signal changing, until the output pin goes to a high-impedance state.
 16. CY7C142/CY7C146 only.
 17. A write operation on Port A, where Port A has priority, leaves the data on Port B's outputs undisturbed until one access time after one of the following: BUSY on Port B goes HIGH.

 Port B's address toggled.

 CE for Port B is toggled.

 RW for Port B is toggled during valid read.
 18. 52-pin PLCC and PQFP versions only.



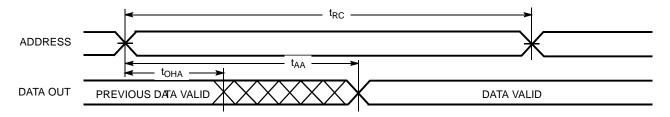
Switching Characteristics Over the Operating Range (Speeds -35, -45, -55) (continued)^[5, 10]

| | | 7C132-35 7C136-35 7C142-35 7C146-35 | | 7C132-45 7C136-45 7C142-45 7C146-45 | | 7C132-55 7C136-55 7C142-55 7C146-55 | | |
|---------------------------|-------------------------------------------------|----------------------------------------------|---------|----------------------------------------------|---------|----------------------------------------------|---------|------|
| Parameter | Description | Min. | Max. | Min. | Max. | Min. | Max. | Unit |
| Write Cycle ^{[1} | [4] | • | | | | | | |
| t _{WC} | Write Cycle Time | 35 | | 45 | | 55 | | ns |
| t _{SCE} | CE LOW to Write End | 30 | | 35 | | 40 | | ns |
| t _{AW} | Address Set-up to Write End | 30 | | 35 | | 40 | | ns |
| t _{HA} | Address Hold from Write End | 2 | | 2 | | 2 | | ns |
| t _{SA} | Address Set-up to Write Start | 0 | | 0 | | 0 | | ns |
| t _{PWE} | R/W Pulse Width | 25 | | 30 | | 30 | | ns |
| t _{SD} | Data Set-up to Write End | 15 | | 20 | | 20 | | ns |
| t _{HD} | Data Hold from Write End | 0 | | 0 | | 0 | | ns |
| t _{HZWE} | R/W LOW to High Z ^[9] | | 20 | | 20 | | 25 | ns |
| t _{LZWE} | R/W HIGH to Low Z ^[9] | 0 | | 0 | | 0 | | ns |
| Busy/Interru | pt Timing | • | | | 1 | | | |
| t _{BLA} | BUSY LOW from Address Match | | 20 | | 25 | | 30 | ns |
| t _{BHA} | BUSY HIGH from Address Mismatch ^[15] | | 20 | | 25 | | 30 | ns |
| t _{BLC} | BUSY LOW from CE LOW | | 20 | | 25 | | 30 | ns |
| t _{BHC} | BUSY HIGH from CE HIGH ^[15] | | 20 | | 25 | | 30 | ns |
| t _{PS} | Port Set Up for Priority | 5 | | 5 | | 5 | | ns |
| t _{WB} | R/W LOW after BUSY LOW ^[16] | 0 | | 0 | | 0 | | ns |
| t _{WH} | R/W HIGH after BUSY HIGH | 30 | | 35 | | 35 | | ns |
| t _{BDD} | BUSY HIGH to Valid Data | | 35 | | 45 | | 45 | ns |
| t _{DDD} | Write Data Valid to Read Data Valid | | Note 17 | | Note 17 | | Note 17 | ns |
| t _{WDD} | Write Pulse to Data Delay | | Note 17 | | Note 17 | | Note 17 | ns |
| Interrupt Tim | ning ^[18] | | | | | | | |
| t _{WINS} | R/W to INTERRUPT Set Time | | 25 | | 35 | | 45 | ns |
| t _{EINS} | CE to INTERRUPT Set Time | | 25 | | 35 | | 45 | ns |
| t _{INS} | Address to INTERRUPT Set Time | | 25 | | 35 | | 45 | ns |
| t _{OINR} | OE to INTERRUPT Reset Time ^[15] | | 25 | | 35 | | 45 | ns |
| t _{EINR} | CE to INTERRUPT Reset Time ^[15] | | 25 | | 35 | | 45 | ns |
| t _{INR} | Address to INTERRUPT Reset Time ^[15] | | 25 | | 35 | | 45 | ns |

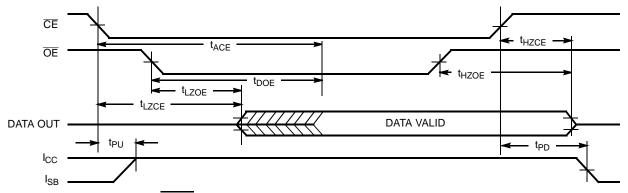


Switching Waveforms

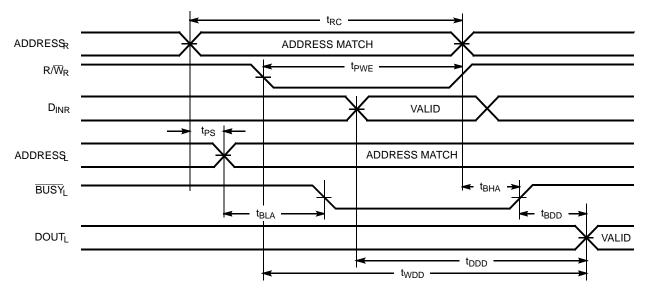
Read Cycle No. 1 (Either Port-Address Access)[19, 20]



Read Cycle No. 2 (Either Port-CE/OE)^[19, 21]



Read Cycle No. 3 (Read with BUSY Master: CY7C132 and CY7C136)



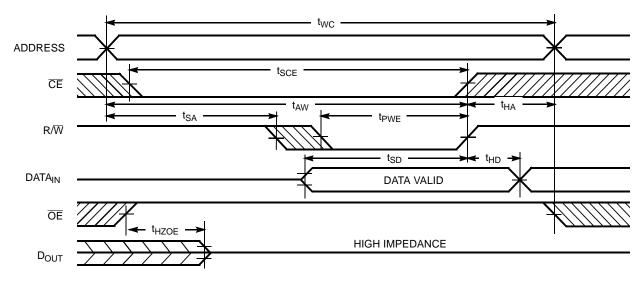
Notes:

R/W is HIGH for read cycle.
 Device is continuously selected, \(\overline{CE} = V_{|L} \) and \(\overline{OE} = V_{|L} \).
 Address valid prior to or coincident with CE transition LOW.

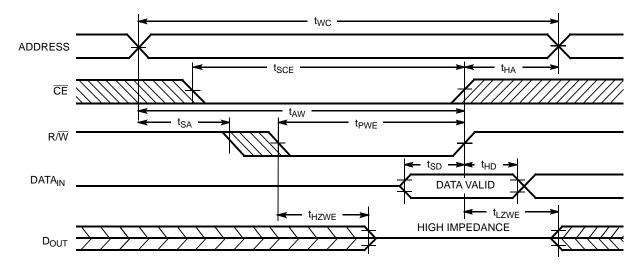


Switching Waveforms (continued)

Write Cycle No.1 (OE Three-States Data I/Os—Either Port)[14, 22]



Write Cycle No. 2 (R/ $\overline{\mathbf{W}}$ Three-States Data I/Os—Either Port)[14, 23]



Notes:

- 22. If \overline{OE} is LOW during a R \overline{W} controlled write cycle, the write pulse width must be the larger of t_{PWE} or $t_{HZWE} + t_{SD}$ to allow the data I/O pins to enter high impedance and for data to be placed on the bus for the required t_{SD}.

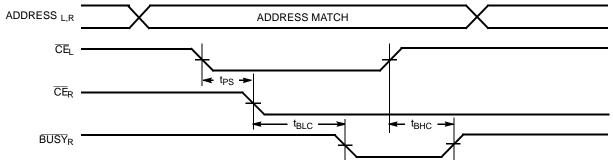
 23. If the CE LOW transition occurs simultaneously with or after the RW LOW transition, the outputs remain in a high-impedance state.



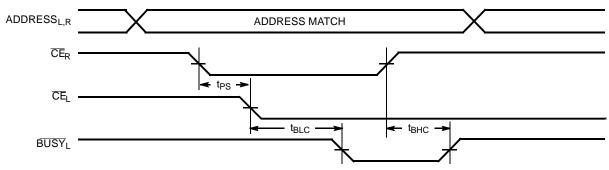
Switching Waveforms (continued)

Busy Timing Diagram No. 1 (CE Arbitration)

CE_LValidFirst:

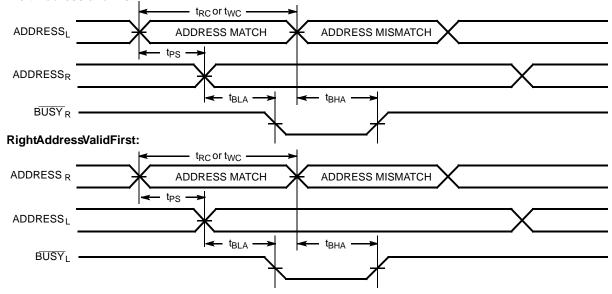


CE_RValidFirst:



Busy Timing Diagram No. 2 (Address Arbitration)

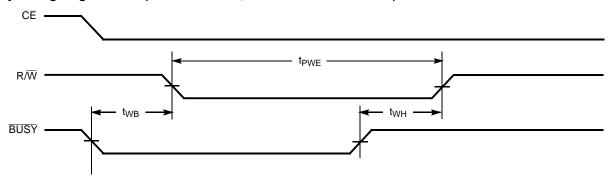
Left Address/alidFirst:





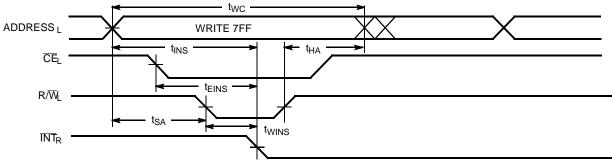
Switching Waveforms (continued)

Busy Timing Diagram No. 3 (Write with BUSY, Slave: CY7C142/CY7C146)

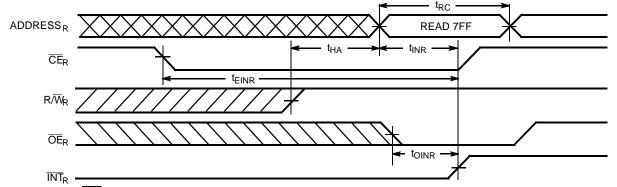


Interrupt Timing Diagrams^[18]

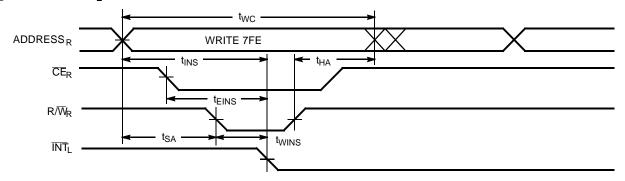
Left Side Sets $\overline{\text{INT}}_{R}$:



Right Side Clears INT_R:



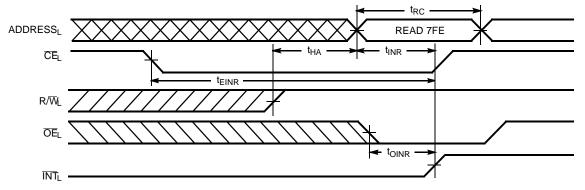
Right Side Sets INT_L:



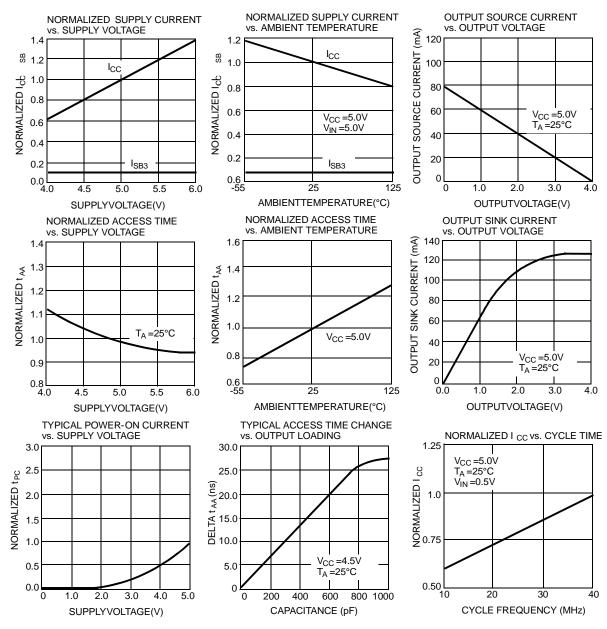


Interrupt Timing Diagrams [18] (continued)

Right Side Clears $\overline{\text{INT}}_{\text{L}}$:



Typical DC and AC Characteristics





Ordering Information

| Speed (ns) | Ordering Code | Package Name | Package Type | Operating Range |
|---------------|---------------|-----------------|-------------------------------------|--------------------|
| 30 | CY7C132-30PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C132-30PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| 35 | CY7C132-35PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C132-35PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| | CY7C132-35DMB | D26 | 48-Lead (600-Mil) Sidebraze DIP | Military |
| 45 | CY7C132-45PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C132-45PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| | CY7C132-45DMB | D26 | 48-Lead (600-Mil) Sidebraze DIP | Military |
| 55 | CY7C132-55PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C132-55PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| | CY7C132-55DMB | D26 | 48-Lead (600-Mil) Sidebraze DIP | Military |
| 15 | CY7C136-15JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C136-15NC | N52 | 52-Pin Plastic Quad Flatpack | |
| 25 | CY7C136-25JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C136-25NC | N52 | 52-Pin Plastic Quad Flatpack | |
| 30 | CY7C136-30JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C136-30NC | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C136-30JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| 35 | CY7C136-35JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C136-35NC | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C136-35JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| | CY7C136-35LMB | L69 | 52-Square Leadless Chip Carrier | Military |
| 45 | CY7C136-45JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C136-45NC | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C136-45JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| | CY7C136-45LMB | L69 | 52-Square Leadless Chip Carrier | Military |
| 55 | CY7C136-55JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C136-55NC | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C136-55JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| | CY7C136-55NI | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C136-55LMB | L69 | 52-Square Leadless Chip Carrier | Military |
| 30 | CY7C142-30PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C142-30PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| 35 | CY7C142-35PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C142-35PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| | CY7C142-35DMB | D26 | 48-Lead (600-Mil) Sidebraze DIP | Military |
| 45 | CY7C142-45PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C142-45PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| | CY7C142-45DMB | D26 | 48-Lead (600-Mil) Sidebraze DIP | Military |
| 55 | CY7C142-55PC | P25 | 48-Lead (600-Mil) Molded DIP | Commercial |
| | CY7C142-55PI | P25 | 48-Lead (600-Mil) Molded DIP | Industrial |
| | CY7C142-55DMB | D26 | 48-Lead (600-Mil) Sidebraze DIP | Military |

Shaded areas contain preliminary information.



Ordering Information (continued)

| Speed (ns) | Ordering Code | Package Name | Package Type | Operating Range |
|---------------|---------------|-----------------|-------------------------------------|--------------------|
| 15 | CY7C146-15JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C146-15NC | N52 | 52-Pin Plastic Quad Flatpack | |
| 25 | CY7C146-25JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C146-25NC | N52 | 52-Pin Plastic Quad Flatpack | |
| 30 | CY7C146-30JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C146-30NC | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C146-30JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| 35 | CY7C146-35JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C146-35NC | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C146-35JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| | CY7C146-35LMB | L69 | 52-Square Leadless Chip Carrier | Military |
| 45 | CY7C146-45JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C146-45NC | N52 | 52-Pin Plastic Quad Flatpack | |
| | CY7C146-45JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| | CY7C146-45LMB | L69 | 52-Square Leadless Chip Carrier | Military |
| 55 | CY7C146-55JC | J69 | 52-Lead Plastic Leaded Chip Carrier | Commercial |
| | CY7C146-55NC | N52 | 2 52-Pin Plastic Quad Flatpack | |
| | CY7C146-55JI | J69 | 52-Lead Plastic Leaded Chip Carrier | Industrial |
| | CY7C146-55LMB | L69 | 52-Square Leadless Chip Carrier | Military |

MILITARY SPECIFICATIONS

Group A Subgroup Testing—DC Characteristics

| Parameter | Subgroups |
|----------------------|-----------|
| V _{OH} | 1, 2, 3 |
| V _{OL} | 1, 2, 3 |
| V _{IH} | 1, 2, 3 |
| V _{IL} Max. | 1, 2, 3 |
| I _{IX} | 1, 2, 3 |
| I _{OZ} | 1, 2, 3 |
| I _{CC} | 1, 2, 3 |
| I _{SB1} | 1, 2, 3 |
| I _{SB2} | 1, 2, 3 |
| I _{SB3} | 1, 2, 3 |
| I _{SB4} | 1, 2, 3 |

Switching Characteristics

| Parameter | Subgroups | | | |
|------------------|-----------------|--|--|--|
| Read Cycle | | | | |
| t _{RC} | 7, 8, 9, 10, 11 | | | |
| t _{AA} | 7, 8, 9, 10, 11 | | | |
| t _{ACE} | 7, 8, 9, 10, 11 | | | |
| t _{DOE} | 7, 8, 9, 10, 11 | | | |
| Write Cycle | | | | |
| t _{WC} | 7, 8, 9, 10, 11 | | | |
| t _{SCE} | 7, 8, 9, 10, 11 | | | |

Switching Characteristics (continued)

| Parameter | Subgroups | |
|---------------------------------|-----------------|--|
| t _{AW} | 7, 8, 9, 10, 11 | |
| t _{HA} | 7, 8, 9, 10, 11 | |
| t _{SA} | 7, 8, 9, 10, 11 | |
| t _{PWE} | 7, 8, 9, 10, 11 | |
| t _{SD} | 7, 8, 9, 10, 11 | |
| t _{HD} | 7, 8, 9, 10, 11 | |
| Busy/Interrupt Timing | | |
| t _{BLA} | 7, 8, 9, 10, 11 | |
| t _{BHA} | 7, 8, 9, 10, 11 | |
| t _{BLC} | 7, 8, 9, 10, 11 | |
| t _{BHC} | 7, 8, 9, 10, 11 | |
| t _{PS} | 7, 8, 9, 10, 11 | |
| t _{WINS} | 7, 8, 9, 10, 11 | |
| t _{EINS} | 7, 8, 9, 10, 11 | |
| t _{INS} | 7, 8, 9, 10, 11 | |
| t _{OINR} | 7, 8, 9, 10, 11 | |
| t _{EINR} | 7, 8, 9, 10, 11 | |
| t _{INR} | 7, 8, 9, 10, 11 | |
| BUSY TIMING | 1 | |
| t _{WB} ^[24] | 7, 8, 9, 10, 11 | |
| t _{WH} | 7, 8, 9, 10, 11 | |
| t _{BDD} | 7, 8, 9, 10, 11 | |
| Note: | ı | |

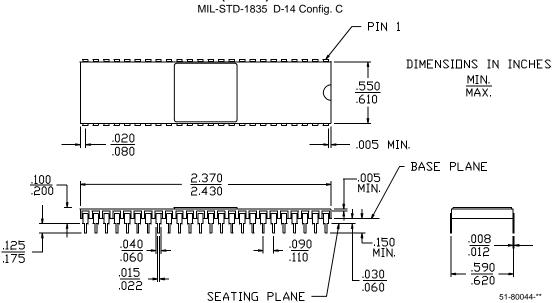
Note:

24. CY7C142/CY7C146 only.

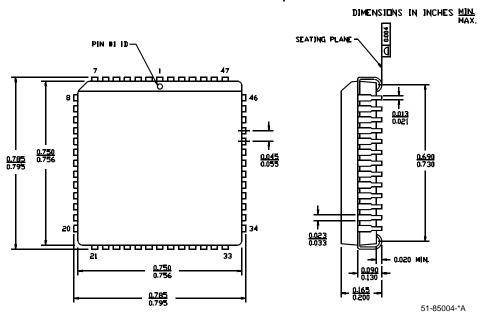


Package Diagrams

48-Lead (600-Mil) Sidebraze DIP D26

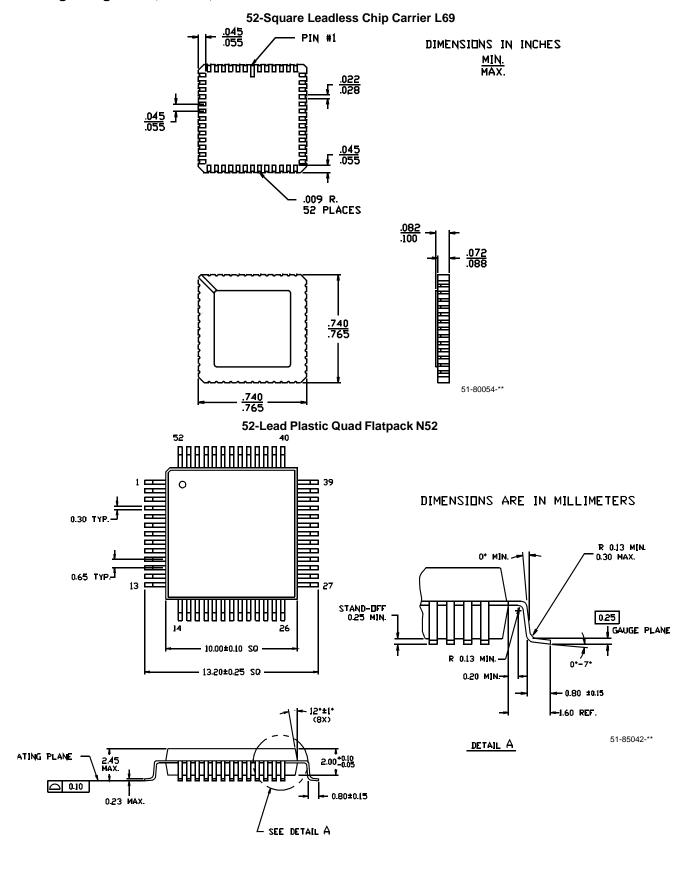


52-Lead Plastic Leaded Chip Carrier J69





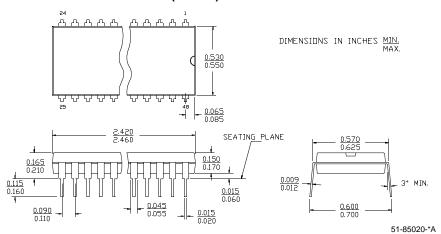
Package Diagrams (continued)





Package Diagrams (continued)

48-Lead (600-Mil) Molded DIP P25



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Document History Page

| Document Title: CY7C132 / CY7C136 / CY7C142 / CY7C146 2K x 8 Dual Port Static RAM Document Number: 38-06031 | | | | | |
|-------------------------------------------------------------------------------------------------------------|---------|------------|--------------------|-------------------------------------------------|--|
| REV. | ECN NO. | Issue Date | Orig. of Change | Description of Change | |
| ** | 110171 | 10/21/01 | SZV | Change from Spec number: 38-06031 | |
| *A | 128959 | 09/03/03 | JFU | Added CY7C136-55NI to Order Information | |
| *B | 236748 | See ECN | YDT | Removed cross information from features section | |